



FAP-120657-FC

1.25Gbps InGaAs PIN/TIA

FEATURES

- High performance 1.25Gbps PIN/TIA
- Automatic gain control (AGC) and differential output
- Minimum 5mV/μW differential responsivity
- Typical sensitivity -26.5dBm
- 0dBm optical overload
- +3.3V or +5V PIN/TIA supply
- Device is electrically isolated from the pigtail housing
- PCB mount pigtail housing
- 9/125/900μm secondary coated fibre pigtail with E2000/APC connector

ABSOLUTE MAXIMUM RATINGS

Optical input power
Supply voltage
Operating temperature
Storage temperature
Soldering temperature 2mm from case for 10 seconds

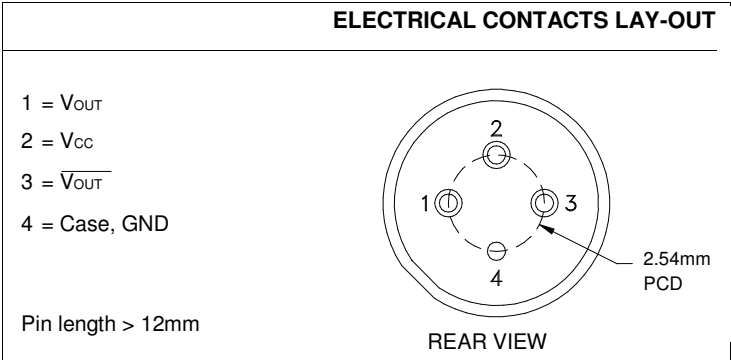
SYMBOL	MIN	MAX	UNITS
P _{IN}		+3	dBm
V _{CC}	-0.5	+6.0	V
T _{AMB}	-40	+85	°C
T _{STG}	-40	+85	°C
T _{SLD}		260	°C



OPTICAL/ELECTRICAL CHARACTERISTICS	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITION
Differential responsivity	R	5	6		mV/μW	P _{IN} = -20dBm, f = 100MHz
Bandwidth	f _c	750	900		MHz	P _{IN} = -20dBm
Rise and fall times (20% to 80%)	t _r / t _f		300		ps	(2), P _{IN} = -3dBm
Low frequency cutoff	f _L		100		kHz	
Operating wavelength range	λ	1270	1300	1560	nm	
Output resistance	Z _o	40	50	62	Ω	
Optical overload	P _{OL}	-3	0		dBm	(1)
Optical sensitivity	P _{MIN}	-24	-26.5		dBm	(1)
Maximum differential output voltage	V _o			800	mV	P _{IN} = -3dBm
Duty cycle distortion			3		%	(2), P _{IN} = -3dBm
Total jitter	J _T		65		ps	(2), (3), P _{IN} = -3dBm
Supply current	I _s		34	50	mA	
Operating voltage	V _{CC}	3.0	3.3	5.5	V	

All values apply at a temperature of 25 °C unless otherwise stated.
Load resistance R_L is = 100Ω (differential) and λ =1300nm unless otherwise stated.

- (1) Measured at 10⁻¹⁰ BER with a 2⁻¹ PRBS at 1.25Gbps.
- (2) Measured with a 1.25Gbps 2⁻¹ PRBS.
- (3) 6σ about the centre eye crossing.



NOTE: This device is susceptible to damage by electrostatic discharge.